

STN851-A

Low voltage fast-switching NPN power transistor

Features

- AEC Q101 compliant
- Very low collector to emitter saturation voltage
- High current gain characteristic
- Fast-switching speed
- Surface-mounting SOT-223 power package in tape and reel

Applications

 High efficiency low voltage switching applications

Description

The device is manufactured in planar technology with "Base Island" layout.

The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

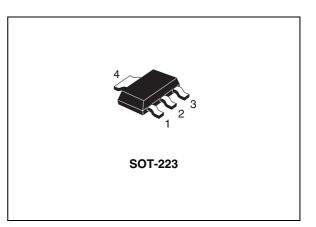


Figure 1. Internal schematic diagram

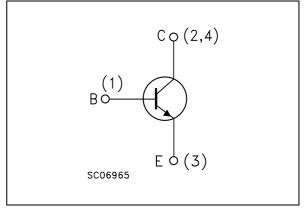


Table 1. Device summary

| Order code | Marking | Package | Packaging |
|------------|---------|---------|---------------|
| STN851-A | N851 | SOT-223 | Tape and reel |

1 Electrical ratings

| Table 2. | Absolute maximum ratings |
|----------|--------------------------|
| | |

| Symbol | Parameter | Value | Unit | |
|------------------|--|------------|------|--|
| V _{CBO} | Collector-base voltage (I _E = 0) | 150 | V | |
| V _{CEO} | Collector-emitter voltage $(I_B = 0)$ | 60 | V | |
| V _{EBO} | Emitter-base voltage (I _C = 0) | 7 | V | |
| ۱ _C | Collector current | 5 | Α | |
| I _{CM} | Collector peak current (t _P < 5 ms) | 10 | Α | |
| Ι _Β | Base current | 1 | Α | |
| I _{BM} | Base peak current (t _P < 5 ms) | 2 | Α | |
| P _{tot} | Total dissipation at T _{amb} = 25 °C | 1.6 | W | |
| T _{stg} | Storage temperature | -65 to 150 | °C | |
| Τ _J | Max. operating junction temperature | 150 | °C | |

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|----------------------|--|-------|------|
| R _{thj-amb} | Thermal resistance junction-ambient ⁽¹⁾ | 78 | °C/W |

1. Device mounted on a p.c.b. area of 1 \mbox{cm}^2



2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

| Table 4. | Electrical characteristics | | | | | | |
|---|---|---|--|------------------------|-------------------------|-------------------------|----------------------|
| Symbol | Parameter | Test co | nditions | Min. | Тур. | Max. | Unit |
| I _{CBO} | Collector cut-off current $(I_E = 0)$ | V _{CB} = 120 V V _{CB} = 120 V | T _c = 100 °C | | | 50 1 | nA μA |
| I _{EBO} | Emitter cut-off current $(I_{C} = 0)$ | V _{EB} = 7 V | | | | 10 | nA |
| V _{(BR)CBO} | Collector-base breakdown voltage (I _E = 0) | Ι _C = 100 μΑ | | 150 | | | v |
| V _{(BR)CEO} ⁽¹⁾ | Collector-emitter breakdown voltage $(I_B = 0)$ | I _C = 10 mA | | 60 | | | v |
| V _{(BR)EBO} | Emitter-base breakdown voltage ($I_{\rm C} = 0$) | I _E = 100 μA | | 7 | | | v |
| V _{CE(sat)} ⁽¹⁾ | Collector-emitter saturation voltage | $I_C = 100 \text{ mA}$ $I_C = 1 \text{ A}$ $I_C = 2 \text{ A}$ $I_C = 5 \text{ A}$ | $I_B = 5 mA$ $I_B = 50 mA$ $I_B = 50 mA$ $I_B = 200 mA$ | | 10 70 140 320 | 50 120 250 500 | mV mV mV mV |
| V _{BE(sat)} ⁽¹⁾ | Base-emitter saturation voltage | I _C = 4 A | I _B = 200 mA | | 1 | 1.15 | V |
| V _{BE(on)} ⁽¹⁾ | Base-emitter on voltage | $I_{\rm C} = 4$ A | $V_{CE} = 1 V$ | | 0.89 | 1 | V |
| $h_{FE}^{(1)}$ | DC current gain | $I_{C} = 10 \text{ mA}$ $I_{C} = 2 \text{ A}$ $I_{C} = 5 \text{ A}$ $I_{C} = 10 \text{ A}$ | V _{CE} = 1 V | 150 150 90 30 | 300 270 140 50 | 350 | |
| f _T | Transition frequency | V _{CE} = 10 V | I _C = 100 mA | | 130 | | MHz |
| C _{CBO} | Collector-base capacitance (I _E = 0) | V _{CB} = 10 V | f = 1 MHz | | 50 | | pF |
| t _{on} t _s t _f | Resistive load Turn-on time Storage time Fall time | $I_{\rm C} = 1 \text{ A}$ $I_{\rm B1} = -I_{\rm B2} = 0.7$ | | | 50 1.35 120 | | ns µs ns |

| Table 4. | Electrical | characteristics |
|----------|------------|-----------------|
|----------|------------|-----------------|

1. Pulse duration = 300 $\mu s,$ duty cycle $\leq 1.5\%$



Figure 2.

57

2.1 Electrical characteristics (curves)

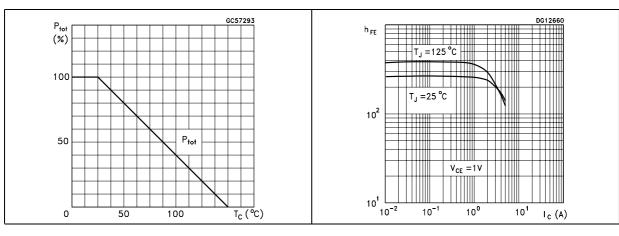


Figure 3.

DC current gain

Collector-emitter saturation

Figure 4. Collector-emitter saturation voltage

Derating curve

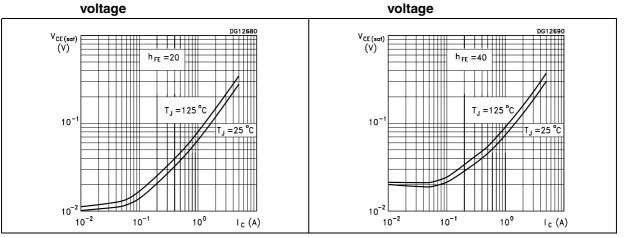


Figure 5.

Figure 6. Base-emitter saturation voltage

Figure 7. Base-emitter on voltage

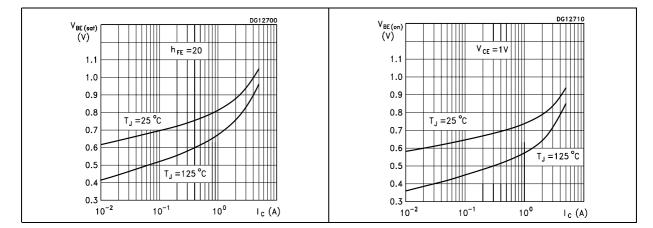


Figure 8. Resistive load switching time

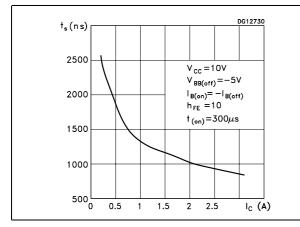


Figure 10. Resistive load switching time

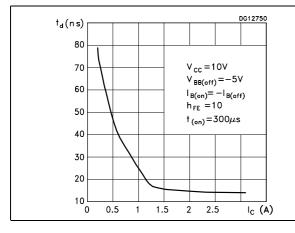


Figure 12. Inductive load switching time

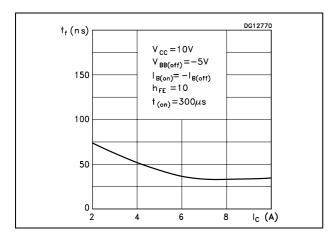


Figure 9. Resistive load switching time

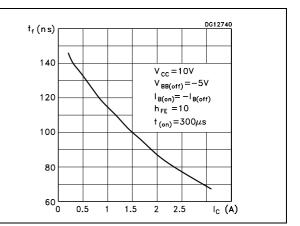
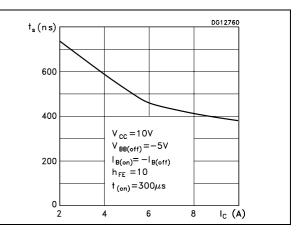


Figure 11. Inductive load switching time



2.2 Test circuit

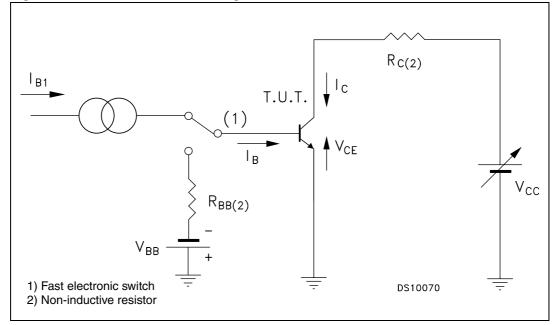


Figure 13. Resistive load switching test circuit

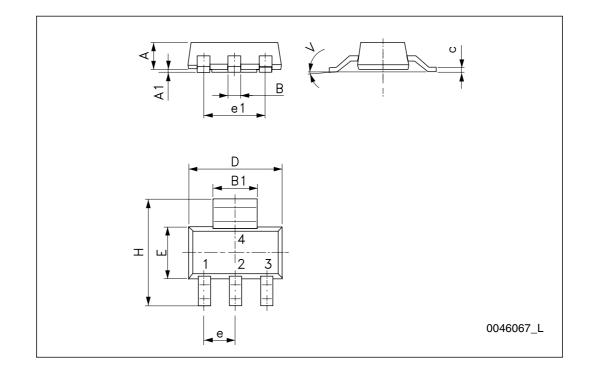


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and products status are available at: www.st.com. ECOPACK is an ST trademark.



| | SOT-223 mechanical data | | | | | |
|------|-------------------------|------|------|--|--|--|
| DIM. | | mm. | | | | |
| DIW. | min. | typ | max. | | | |
| A | | | 1.80 | | | |
| A1 | 0.02 | | 0.1 | | | |
| В | 0.60 | 0.70 | 0.85 | | | |
| B1 | 2.90 | 3.00 | 3.15 | | | |
| с | 0.24 | 0.26 | 0.35 | | | |
| D | 6.30 | 6.50 | 6.70 | | | |
| е | | 2.30 | | | | |
| e1 | | 4.60 | | | | |
| E | 3.30 | 3.50 | 3.70 | | | |
| н | 6.70 | 7.00 | 7.30 | | | |
| V | | | 10 ° | | | |





4 Revision history

Table 5.Document revision history

| Date | Revision | Changes |
|-------------|----------|-------------|
| 16-Mar-2009 | 1 | First issue |



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

STMicroelectronics: STN851-A